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Research Article

Electron Spectrum and Tunneling Current of the Toroidal and Helical Graphene Nanoribbon-Quantum Dots Contact

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We study the electron spectrum and the density of states of long-wave electrons in the curved graphene nanoribbon based on the Dirac equation in a curved space-time. The current-voltage characteristics for the contact of nanoribbon-quantum dot have been revealed. We also analyze the dependence of the specimen properties on its geometry.

1. Introduction

The problem of modified graphene properties attracts a considerable attention of researchers [1, 2] because the “pure” graphene has no energy gap in the band structure and, therefore, the creation of different structures (e.g., analogs of transistors) is extremely difficult. However, the situation becomes more promising when various modifications of the specimen are introduced. As an example, we consider the modified graphene, for example, graphene nanoribbon, which have quantized electron energy spectrum due to the limited space in one dimension, which in turn can lead to the formation of the energy gap. Furthermore, we know that the graphene has a naturally wave-like curved surface due to the instability of the planar structure of its sheets [3, 4]. All of the above reasons have stimulated the study of different modifications of a curved graphene [5, 6]. The long-wave approximation, which is widely used to describe the properties of electrons in graphene, leads to an analog of the Dirac equation, which in turn makes it easy to produce generalization to the case when the graphene surface is curved. Note that in this case the degeneracy in the Dirac points is removed and therefore it becomes possible to create

various structures with different band gaps. Consideration of the Dirac equation for curved graphene [5] also shows a change in the density of states of electrons and, therefore, it is possible to change the whole set of electrical characteristics of the graphene sample. Apparently, the easiest way to experimentally verify the changes in the density of states is to study the tunneling current [7], for example, through the contact with quantum dots. Quantum dots are still rather “young” objects of study, but their use in various fields of science and technology is obviously extremely promising (from the design of lasers and new generation displays to building qubits) [8].

2. Basic Equations and Spectrum of Electrons

We consider the graphene nanoribbon, which is curved along the toroidal and the helical surfaces, as presented in Figure 1.

Properties of electrons in the graphene nanoribbons in the long-wave approximation in the vicinity of the Dirac point will be described on the basis of the Dirac equation generalized for the case of a curved space-time [9]:

$$\gamma^\mu (\partial_\mu - \Omega_\mu) \Psi = 0. \quad (1)$$

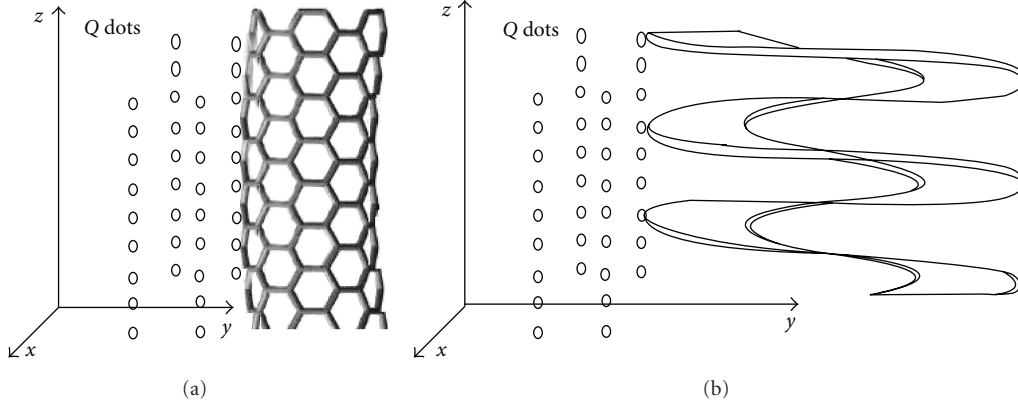


FIGURE 1: Geometry of a problem; (a) toroidal nanoribbon, (b) helical nanoribbon.

Here and below the repeated indices assume summation; ∂_μ is the partial derivative with respect to coordinate μ , Ω_μ is the component of the spin connection, and $\Psi = \begin{pmatrix} \phi \\ \varphi \end{pmatrix}$ is the wave function (column vector) consisting of wave functions describing the electrons from different sublattices near the Dirac point.

As is known [9, 10], if we are given the metric tensor

$$ds^2 = g_{\alpha\beta} dx^\alpha dx^\beta, \quad (2)$$

$$g_{\alpha\beta} g^{\beta\gamma} = \delta_\alpha^\gamma$$

(δ_α^γ : delta Kronecker symbol) then, we can define the field frames (tetrads):

$$g_{\alpha\beta} = e_\alpha^a e_\beta^b \eta_{ab},$$

$$g^{\alpha\beta} = e_a^\alpha e_b^\beta \eta^{ab}, \quad (3)$$

$$\eta_{ab} \eta^{bc} = \delta_a^c,$$

where, for the two-dimensional curved surface, we have $\eta_{ab} = \text{diag}(1, -1, -1)$. Then,

$$\Omega_\mu = \frac{1}{4} \gamma_a \gamma_b e_\lambda^\alpha g^{\lambda\sigma} (\partial_\mu e_\sigma^b - \Gamma_{\mu\sigma}^\lambda e_\lambda^b),$$

$$\Gamma_{\mu\sigma}^\lambda = \frac{1}{2} g^{\lambda\nu} (g_{\sigma\nu,\mu} + g_{\nu\mu,\sigma} - g_{\mu\sigma,\nu}), \quad (4)$$

$$\gamma^\mu = e_a^\mu \gamma_a.$$

Using the torus and the helical parameterization

$$x = (R + r \cos x_1) \cos x_2,$$

$$y = (R + r \cos x_1) \sin x_2,$$

$$z = r \sin x_1,$$

$$x = x_1 \cos x_2,$$

$$y = x_1 \sin x_2,$$

$$z = h \cdot x_2, \quad (5)$$

we find that the metrics on the torus surface and the helicoid is

$$ds^2 = dx_0^2 - r^2 dx_1^2 - (R + r \cos x_1)^2 dx_2^2, \quad (6)$$

$$ds^2 = dx_0^2 - dx_1^2 - (h^2 + x_1^2) dx_2^2.$$

Note that all the Christoffel symbols are equal to zero, except Γ_{12}^2 and Γ_{22}^1 . For the torus, we have $\Omega_0 = 0$, $\Omega_1 = 0$, $\Omega_2 = (1/2)\gamma_1\gamma_2 f'/r$ ($f = R + r \cos x_1$, and $f' = \partial f/\partial x_1$), while in the case of helicoid $\Omega_0 = 0$, $\Omega_1 = 0$, and $\Omega_2 = (1/2)\gamma_1\gamma_2(x_1/(h^2 + x_1^2))^{1/2}$.

Choosing $\gamma_0 = \sigma_3$, $\gamma_1 = -i\sigma_2$, and $\gamma_2 = -i\sigma_1$, where σ are the Pauli matrices, we obtain the following system of equations:

$$V_F^{-1} \partial_t \varphi = -\frac{1}{r^2} \partial_{x_1} \Psi - \frac{i}{f^2} \partial_{x_2} \Psi + \frac{f'}{2f^2 r} \Psi,$$

$$V_F^{-1} \partial_t \varphi = -\frac{1}{r^2} \partial_{x_1} \varphi + \frac{i}{f^2} \partial_{x_2} \varphi + \frac{f'}{2f^2 r} \varphi,$$

$$V_F^{-1} \partial_t \varphi + \partial_{x_1} \Psi + \frac{i}{h^2 + x_1^2} \partial_{x_2} \Psi - \frac{x_1}{2(h^2 + x_1^2)^{3/2}} \Psi = 0,$$

$$-V_F^{-1} \partial_t \Psi - \partial_{x_1} \varphi + \frac{i}{h^2 + x_1^2} \partial_{x_2} \varphi - \frac{x_1}{2(h^2 + x_1^2)^{3/2}} \varphi = 0. \quad (7)$$

Here, V_F is the Fermi velocity for planar graphene, $\partial_0 = V_F^{-1} \partial_t$. Note that since the metric (6) admits two Killing vectors corresponding to translations along x_0, x_2 , the solution (7) can be found in the form

$$\begin{pmatrix} \varphi \\ \Psi \end{pmatrix} \rightarrow \begin{pmatrix} \varphi(x_1) \\ \Psi(x_1) \end{pmatrix} e^{iEt - ikx_2}, \quad (8)$$

which finally gives

$$\begin{aligned}\Psi'' &= \left(-\frac{E^2 r^4}{V_f^2} + \frac{k_n^2 r^4}{f^4} \right) \Psi + \frac{r f'}{2f^2} \Psi' \\ &+ \left(\frac{2k_n r^2 f'}{f^3} + \frac{r f''}{2f^2} - \frac{r f'^2}{f^3} - \frac{r^2 f'^2}{4f^4} \right) \Psi, \\ \Psi'' &= \left(-\frac{\varepsilon^2}{V_f^2} + \frac{k^2}{(h^2 + x_1^2)^2} \right) \Psi \\ &+ \left(-\frac{k x_1}{(h^2 + x_1^2)^{5/2}} + \frac{x_1^2}{4(h^2 + x_1^2)^3} \right) \Psi.\end{aligned}\quad (9)$$

Note that the wave vector k is found from the boundary conditions at the ends of the nanoribbon. In our particular case, we have chosen the armchair-type ribbon [6] and

$$k_n = \frac{2\pi}{3a_0} \left(\frac{2M + 1 + n}{2M + 1} \right), \quad (10)$$

where a_0 is the distance between the atoms in the carbon lattice, M is the number of atoms along nanoribbon axis, and n is the quantum number. We can consider (9) as a Schrodinger equation with perturbation

$$\begin{aligned}\hat{V}_{\text{Torus}} &= \left[\left(\frac{2k_n r^2 f'}{f^3} + \frac{r f''}{2f^2} - \frac{r f'^2}{f^3} - \frac{r^2 f'^2}{4f^4} \right) + \frac{r f'}{2f^2} \partial_x \right], \\ \hat{V}_{\text{Helicoid}} &= \left(-\frac{k x_1}{(h^2 + x_1^2)^{5/2}} + \frac{x_1^2}{4(h^2 + x_1^2)^3} \right).\end{aligned}\quad (11)$$

In this case, the spectrum of perturbation looks like

$$E = \pm \sqrt{k_n^2 + k_y^2}. \quad (12)$$

Expanding the functions in the denominator in Taylor series to the second order, we calculate the first perturbation correction to the spectrum, \hat{V}_{Torus} and $\hat{V}_{\text{Helicoid}}$, as follows:

$$E_1 = \int \Psi^* \hat{V} \Psi dx, \quad \Psi_n = A \cdot \text{Sin}(k_n x_1). \quad (13)$$

The integration is performed from 0 to $L = (3M + 1)a_0$, and the corrections are as follows:

$$\begin{aligned}E_1 &= \frac{2}{L} \left\{ -\frac{r^2}{4R^2} \text{Sin}(L) + \frac{r^2}{8R^2} \left(1 - \frac{1}{k_n} \right) \frac{\text{Sin}(2k_n - 1)L}{(2k_n - 1)} \right. \\ &\quad \left. + \frac{r^2}{8R^2} \left(1 + \frac{1}{k_n} \right) \frac{\text{Sin}(2k_n + 1)L}{(2k_n + 1)} \right\}, \\ E_1 &= \frac{2}{L} \left\{ \left(-\frac{kL^2}{4h^5} + \frac{k}{4h^5 k_n^4} + \frac{h^{-2/3} L^3}{24} \right) \right. \\ &\quad + \text{Sin}(2k_n L) \left(\frac{kL}{4h^5 k_n} + h^{-2/3} \left(\frac{1}{32k_n^3} - \frac{L^2}{16k_n} \right) \right) \\ &\quad \left. + \text{Cos}(2k_n L) \left(\frac{-k}{4h^5 k_n^4} + \frac{h^{-2/3} L}{16k_n^2} \right) \right\}.\end{aligned}\quad (14)$$

The dependence of the perturbations on the atom numbers along the nanoribbons M is presented in Figure 2.

The dependence shown in Figure 2(a) is rather complex, which is associated with the quantization of the electron spectrum in graphene nanoribbons in accordance with (10). It should be noted that the dependence of the energy gap in carbon nanotubes of zigzag type is pretty much similar, which also arises from the quantization of the electron spectrum in the direction along the circumference of the nanotube. The calculations (Figure 2(b)) show that the value of the helicoids parameterization h influences most strongly the correction to the energy (as well as its sign).

3. Tunneling Characteristics

The Hamiltonian of the system of electrons can be written in the following form:

$$H = \sum_p E_p^A a_p^\dagger a_p + \sum_q E_q^B b_q^\dagger b_q + \sum_{pq} T_{pq} (a_p^\dagger b_q + b_q^\dagger a_q), \quad (15)$$

where a_p^\dagger, a_p are the electron creation and annihilation operators with momentum p in the carbon nanoribbons, E_p^A is the electron spectrum of the carbon nanoribbons (12) with taking into account (14), T_{pq} is the matrix element of tunneling operator between p and q states, b_q^\dagger, b_q are the electron creation and annihilation operators with momentum q in a substance which is in a contact with a carbon nanoribbon, and E_q^B is the electron spectrum of another substance. It should be noted that p and q are multi-indices in (15). So, for graphene nanoribbon (further, we consider an arm-chair nanoribbon only), $p = (p_y, n)$, $n = 0, 1, \dots, M - 1$. Multi-index q is determined by the substance which contacts with carbon nanoribbon and, for example, for quantum dots $q = (p_x, p_y, p_z)$, whereas for grapheme $q = (p_x, p_y)$. A consideration of the external electric field \vec{E} (and choosing $\vec{E} = -(1/c)(\partial \vec{A}/\partial t)$) can be carried out by the replacement $p \rightarrow p - eA/c$.

Tunneling current is considered to be given by

$$J = ie \sum_{pq} (a_p^\dagger b_q - b_q^\dagger a_p). \quad (16)$$

With a gauge transformation [11],

$$a_p \rightarrow S^{-1} a_p S,$$

$$S = \exp \left(ieVt \sum_p a_p^\dagger a_p \right), \quad (17)$$

where V is the applied voltage and e is the electron charge. Formally, it is possible to reduce a problem of calculation of the current-voltage characteristics to the calculation of the operator response

$$J_t = ie \sum_{pq} (a_p^\dagger b_q e^{ieVt} - b_q^\dagger a_q e^{-ieVt}) \quad (18)$$

on the external influence [11]

$$H_t = \sum_{pq} T_{pq} (a_p^\dagger b_q e^{ieVt} + b_q^\dagger a_q e^{-ieVt}). \quad (19)$$

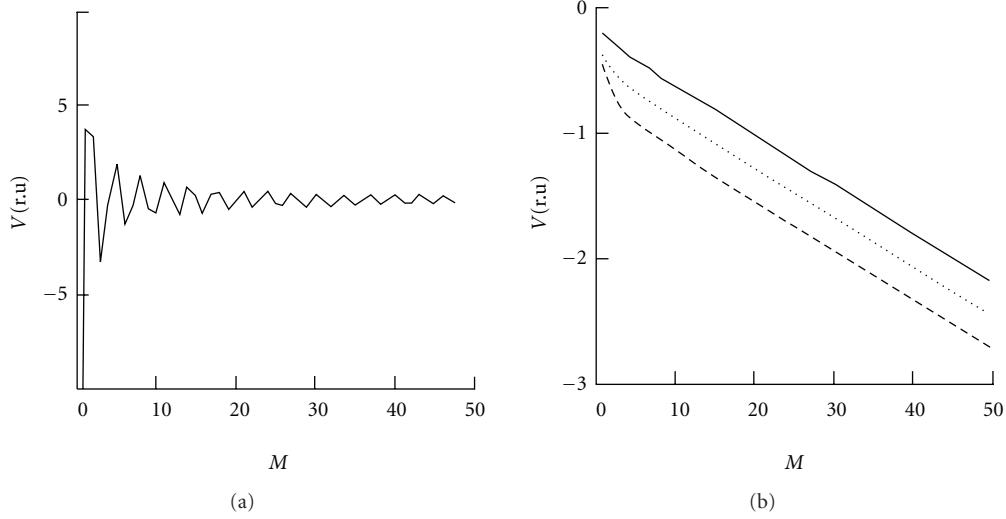


FIGURE 2: Dependence of the correction to the energy V caused by the perturbation \hat{V} on atoms number along nanoribbon axis M : (a) for torus ($r/R = 0.1$, $n = 1$); (b) for helicoid ($h = 1.5$): (a) $n = 1$, (b) $n = 2$, (c) $n = 3$.

The solution was obtained within the framework of the Kubo theory:

$$J = 4\pi e |T|^2 \int_{-\infty}^{\infty} dE v_A(E + eV) v_B(E) (n_f(E) - n_f(E + eV)),$$

$$v_A(E) = \sum_p \delta(E - E_p^A); \quad v_B(E) = \sum_q \delta(E - E_q^B),$$
(20)

where $\delta(x)$ is the Dirac delta function, $v_{A(B)}(E)$ is the tunneling density of states, and $n_f(E)$ is the equilibrium number of fermions with the energy E . The approximation of a “rough” contact is hereinafter used, so that $T_{pq} = T$ (this imposes certain restrictions on the contact geometry, i.e., for the case discussed below means that nanoribbon should be perpendicular to the contact material surface). For definiteness, we choose the dispersion law for the graphene nanoribbons given by (12) and (14) and the dispersion law for the quantum dots as the contact material being

$$E_q^A = \varepsilon_0 - \Delta \cos(p),$$
(21)

where ε_0 is the electron energy of a quantum well, Δ is the tunneling integral determined by the overlap of electron wave functions in the adjacent wells, and the momentum p is directed along the axis Z .

Equation (20) under study has been solved numerically. The current-voltage characteristic of the contact is presented in Figure 3.

Figure 3 shows the asymmetric behavior of current versus voltage applied to the contact. This is due to both the peculiarities of the electronic structure (density of states) of the metal and graphene nanoribbon and the processes of carrier recombination in the transition contact, which dominate over the thermal processes when $V > 0$. The resulting dependence may have important practical applications in the study of nanocontacts and the design

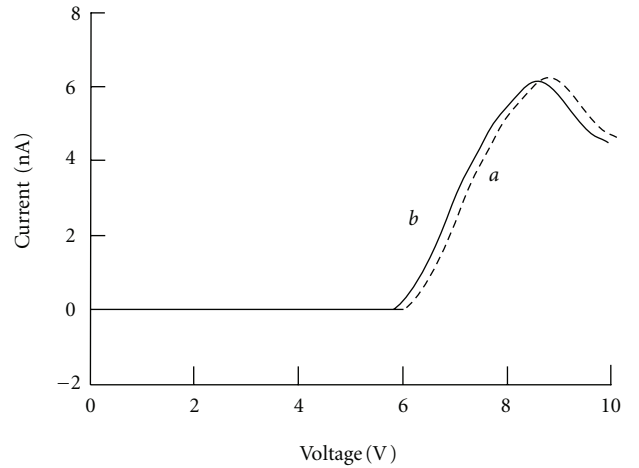


FIGURE 3: The current-voltage characteristic of the contact: curved graphene nanoribbon-quantum dots: (a) for torus; (b) for helicoid.

of tunnel diodes based on graphene nanoribbons. Also, the region with negative differential resistance was observed for some values of V . The presence of such region allows the use of a tunnel diode as a high-speed switch.

4. Conclusion

- (1) An effective equation, which describes the electrons in a curved graphene nanoribbon and the tunneling contact nanoribbon-quantum dot has been obtained.
- (2) The dependence of the electron spectrum on the geometry has been revealed. In general, the first perturbation correction to the spectrum is defined by the atoms number along the nanoribbon axis M and by the parametric coefficient, which describes

the “curvature” of nanoribbon, r/R (in the torus nanoribbon case), and the step for helical nanoribbon h .

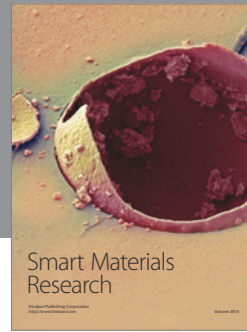
- (3) The current-voltage characteristics for the contact graphene nanoribbon-quantum dots was constructed; the regions with negative differential conductivity were found.

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